

### Measurement Module for Strain Gage and LVDT/RVDT

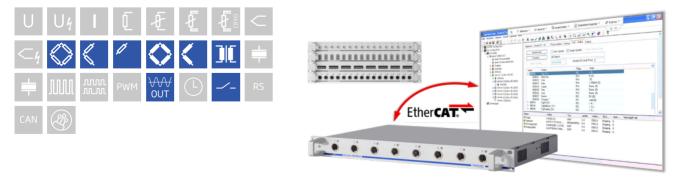
Q.raxx EC slimline is Q.series' highest density 19" 1U rackmount EtherCAT DAQ system - the ideal solution for boom box installations or applications that require maximum channel density and custom sensor terminations. The Q.raxx EC slimline utilizes an integrated EtherCAT bus coupler for communication and is capable of sampling up to 100 kHz with short cycle times and low jitter for accurate synchronization. In addition to available variations, the Q.raxx EC slimline is fully customizable to your specific measurement needs.

- FTP Server and FTP Client functionality configurable function
- Optional fieldbus interface EtherCAT, EtherCAT according specification ETG, 254 read and 254 write variable with 10 kHz
- Ethernet interface for configuration and data output FTP, TCP/IP, UDP
- High data rate over Ethernet, 16 real variables with 10 kHz (block transfer), 64 real variables with 300 Hz (online)
- Data buffer memory dyn. 16 MByte (RAM), stat. 128 MByte (flash) data buffer at block transfer of measurements
- PAC functionality



### **Key Features**

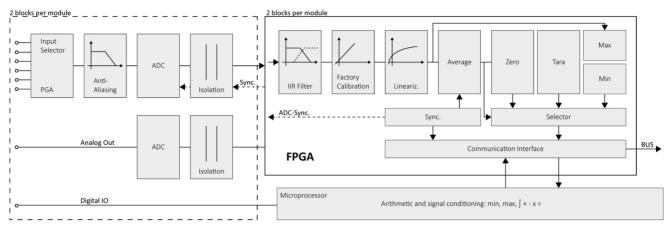
- 8 Analog input channels strain gauge and inductive half and full bridges, LVDT, RVDT quarter bridge with completion terminal
- DC and carrier frequency (CF) principle
   2.5 and 5 VDC excitation, 2.5 and 5 VDCeff excitation carrier frequency,
   600 Hz or 4.8 kHz configurable per channel
- 8 Analog output channels
   ±10 VDC, 10 kHz update rate per channel
- High-accuracy digitization
   24-bit ADC, 10 kHz sample rate per channel
- 4 digital I/Os input: state, tare, memory reset, output: state, alarm, threshold
- 16 Digital inputs or outputs status, trigger, tare, alarm, command
- Signal conditioning linearization, filtering, average, scaling, min/max, RMS, arithmetic, alarm
- 3-Way galvanic isolation
   500 VDC channel to channel, channel to power supply, and channel to bus





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## Block diagram



## **Technical Data**

### Analog Input Slimline

| 8  |   |
|--|---|
| 0.02 % typical   |   |
| 0.05 % in controlled environment <sup>1</sup>                          |   |
| 0.1 % in industrial area²  |   |
| 0.02 % typical full-scale  |   |
| 0.01 % typical (within 24 hrs)   |   |
| >10 MΩ   |   |
| 500 VDC channel to channel, to power supply, channel to bus $^{\rm 3}$ |   |
|  | 0.05 % in controlled environment <sup>1</sup> |

 $^{\rm 1}\,$  according to EN 61326 2006: appendix B

<sup>2</sup> according to EN 61326 2006: appendix A

<sup>3</sup> noise pulses up to 1000 VDC, continuous up to 250 VDC

### Analog to Digital Conversion

| Resolution           | 24-bit  |
|----------------------|---|
| Sample rate          | 10 kHz per channel  |
| Modulation method    | sigma-delta   |
| Anti-aliasing filter | 2 kHz, 3rd order (DC excitation)<br>1 kHz, 3rd order (4.8 kHz CF excitation)<br>100 Hz, 3rd order (600 Hz CF excitation)  |
| Digital filters      | Infinite impulse response (IIR), low-pass, high-pass, band-pass, band-stop, to 8th order Butterworth or Bessel, frequency range 0.1 Hz to 1 kHz in steps of 0.1 (adjustable via software) |
| Averaging            | configurable or automatic according to the user-defined data rate   |



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### Analog Output

| Channels                  | 2                        |                            |
|---------------------------|--------------------------|----------------------------|
| Accuracy                  | 0.02 % typical           |                            |
| Voltage output            | ±10 VDC                  |                            |
| Allowable load resistance | >2 kΩ                    |                            |
| Long-term drift           | <1 mV / 24 hrs           | <2.5 mV / 8000 hrs         |
| Temperature drift         | <1 mV /10 K Offset drift | < 0.05 % / 10 K Gain drift |
| Noise voltage             | <2 mV at 10 Hz           | <10 mV at 1 kHz            |

### Digital Input & Output

| Channels             | 4 configurable I/Os                     |
|----------------------|---|
| Mode(s) of operation | status                                  |
| Logic voltage        | <2 VDC (Low)<br>>10 VDC (High)          |
| Input type           | PNP (current sinking)                   |
| Input voltage        | 30 VDC max.                             |
| Output voltage       | 10 to 30 VDC (external supply required) |
| Contact              | open drain p-channel MOSFET             |
| Load capacity        | 30 VDC / 100 mA (ohmic load)            |

### Strain Gage Measurement

| Bridge configuration(s)           | resistive full-bridge (4/6<br>resistive half-bridge (3/5<br>resistive quarter-bridge | -wire)      | , with bridge completion                               | terminal)                             |
|-----------------------------------|--|-------------|--|---------------------------------------|
| Allowable sensor cable length     | < 300 m (DC and 600 Hz (<br><100 m <sup>1</sup> (4.8 kHz CF exc                      | ,           |  |                                       |
| Shunt resistor                    | 100 kΩ internal resistor   |             |  |                                       |
| Bridge excitation                 | 2.5 - 5 VDC<br>2.5 - 5 Veff (Carrier Frequency)                                      |             |  |                                       |
| Bridge excitation stability       | <0.01% / 24 hrs  |             |  |                                       |
| Bridge excitation drift           | <0.02% / 10 K  |             |  |                                       |
|                                   | 5 VDC  | 5 Veff (CF) | 2.5 VDC  | 2.5 Veff (CF)                         |
| Allowable sensor resistance       | >300 Ω   | > 300 Ω     | >100 Q   | >100 Q                                |
| Input range                       | ±1.25 mV/V   | ±1.25 mV/V  | ±2.5 mV/V  | ±2.5 mV/V                             |
|                                   | ±2.5 mV/V  | ±2.5 mV/V   | ±5 mV/V  | ±5 mV/V                               |
|                                   | ±25 mV/V   | ±25 mV/V    | ±50 mV/V   | ±50 mV/V                              |
|                                   | ±50 mV/V   | ±50 mV/V    | ±100 mV/V  | ±100 mV/V                             |
|                                   | ±100 mV/V  | ±100 mV/V   | ±200 mV/V  | ±200 mV/V                             |
|                                   | ±200 mV/V  | ±200 mV/V   | ±400 mV/V  | ±400 mV/V                             |
|                                   | ±500 mV/V  | ±500 mV/V   | ±1000 mV/V   | ±1000 mV/V                            |
| Long-term stability               | <0.2 µV/V / 24 hrs (DC excitation)<br><0.1 µV/V / 24 hrs (CF excitation)             |             | <pre>&lt;2 µV/V / 8000 hrs &lt;1 µV/V / 8000 hrs</pre> | · · · · · · · · · · · · · · · · · · · |
| emperature drift (range 2.5 mV/V) | <0.2 µV/V / 10 K Offset drift  |             | < 0.05 % / 10 K Gain                                   | drift                                 |
| Signal-to-noise ratio             | < 0.3 µV/V at 10 Hz  |             | <1 µV/V at 100 Hz                                      |                                       |

 $^{\rm 1}\,$  low capacity sensor cable is strongly recommended



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### LVDT/RVDT Measurement

| 4- / 6-wire                   |   |
|-------------------------------|---|
| 5 Veff                        | 2.5 Veff  |
| >300 Ω                        | >100 Ω  |
| ±1.25 mV/V                    | ±2.5 mV/V   |
| ±2.5 mV/V                     | ±5 mV/V   |
| ±25 mV/V                      | ±50 mV/V  |
| ±50 mV/V                      | ±100 mV/V   |
| ±100 mV/V                     | ±200 mV/V   |
| ±200 mV/V                     | ±400 mV/V   |
| ±500 mV/V                     | ±1000 mV/V  |
| <100 m <sup>1</sup>           |   |
| <0.1 µV/V / 24 hrs            | <1 µV/V / 8000 hrs  |
| <0.2 µV/V / 10 K Offset drift | < 0.05 % / 10 K Gain drift  |
| < 0.3 µV/V at 10 Hz           | <1 µV/V at 100 Hz   |
|                               | 5 Veff<br>> 300 Ω<br>±1.25 mV/V<br>±2.5 mV/V<br>±25 mV/V<br>±50 mV/V<br>±100 mV/V<br>±100 mV/V<br>±200 mV/V<br>(100 m <sup>1</sup><br><0.1 μV/V / 24 hrs<br><0.2 μV/V / 10 K Offset drift |

<sup>1</sup> low capacity sensor cable is strongly recommended

### Digital to Analog Conversion

| Resolution    | 16-bit             |
|---------------|--------------------|
| Update rate   | 10 kHz per channel |
| Settling time | zμs                |

### Power Supply

| Input voltage           | 10 to 30 VDC, overvoltage and overcurrent protection |
|-------------------------|--|
| Power consumption       | 2.5 W (approx.)                                      |
| Input voltage influence | <0.001 % / V   |

### **Environmental Specifications**

| Electromagnetic compatibility (EMC) | according to IEC 61000-4 and EN 55011 |
|-------------------------------------|---------------------------------------|
| Operating temperature               | -20°C to +60°C                        |
| Storage temperature                 | -40°C to +85°C                        |
| Relative humidity                   | 5 - 95 % at 50°C (non-condensing)     |

### Remarks

| Validity of all listed specifications are subject to a warm-up period of at least 45 minutes |  |
|--|--|
| Specifications subject to change without notice  |  |

### Mechanical information

| Туре                     | 19" Standard, 1 Unit |
|--------------------------|----------------------|
| Measurements (W x H x D) | 444 x 44 x 260 mm    |
| Weight                   | approx. 2000 g       |

## Measurement Module for Strain Gage and LVDT/RVDT



### Ordering Information

Article number 463021

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